

2N3906

General Purpose Transistors

PNP Silicon

Features

- Pb-Free Packages are Available*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|----------------|-------------|----------------------------|
| Collector – Emitter Voltage | V_{CEO} | 40 | Vdc |
| Collector – Base Voltage | V_{CBO} | 40 | Vdc |
| Emitter – Base Voltage | V_{EBO} | 5.0 | Vdc |
| Collector Current – Continuous | I_C | 200 | mA _{dc} |
| Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 625 5.0 | mW mW/ $^\circ\text{C}$ |
| Total Power Dissipation @ $T_A = 60^\circ\text{C}$ | P_D | 250 | mW |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 1.5 12 | W mW/ $^\circ\text{C}$ |
| Operating and Storage Junction Temperature Range | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

THERMAL CHARACTERISTICS (Note 1)

| Characteristic | Symbol | Max | Unit |
|---|-----------------|------|---------------------------|
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 200 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 83.3 | $^\circ\text{C}/\text{W}$ |

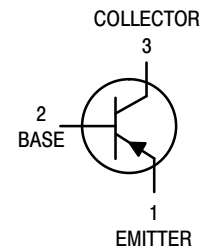
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates Data in addition to JEDEC Requirements.

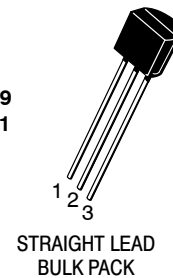


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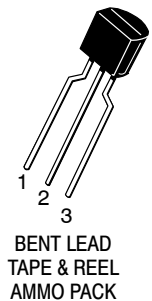
<http://onsemi.com>



TO-92
CASE 29
STYLE 1

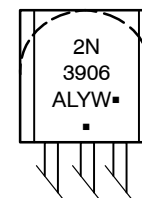


STRAIGHT LEAD
BULK PACK



BENT LEAD
TAPE & REEL
AMMO PACK

MARKING DIAGRAM



- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

2N3906

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

OFF CHARACTERISTICS

| | | | | | |
|--|---|---------------|-----|----|------|
| Collector – Emitter Breakdown Voltage (Note 2) | $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ | $V_{(BR)CEO}$ | 40 | – | Vdc |
| Collector – Base Breakdown Voltage | $(I_C = 10 \text{ }\mu\text{Adc}, I_E = 0)$ | $V_{(BR)CBO}$ | 40 | – | Vdc |
| Emitter – Base Breakdown Voltage | $(I_E = 10 \text{ }\mu\text{Adc}, I_C = 0)$ | $V_{(BR)EBO}$ | 5.0 | – | Vdc |
| Base Cutoff Current | $(V_{CE} = 30 \text{ Vdc}, V_{EB} = 3.0 \text{ Vdc})$ | I_{BL} | – | 50 | nAdc |
| Collector Cutoff Current | $(V_{CE} = 30 \text{ Vdc}, V_{EB} = 3.0 \text{ Vdc})$ | I_{CEX} | – | 50 | nAdc |

ON CHARACTERISTICS (Note 2)

| | | | | | | |
|--|--|---------------|-----------|--------------|-----|---|
| DC Current Gain | $(I_C = 0.1 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ | h_{FE} | 60 | – | – | |
| | $(I_C = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ | | 80 | – | – | |
| | $(I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ | | 100 | 300 | – | – |
| | $(I_C = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ | | 60 | – | – | – |
| | $(I_C = 100 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ | | 30 | – | – | – |
| Collector – Emitter Saturation Voltage | $(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$ | $V_{CE(sat)}$ | – | 0.25 0.4 | Vdc | |
| Base – Emitter Saturation Voltage | $(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$ | $V_{BE(sat)}$ | 0.65 – | 0.85 0.95 | Vdc | |

SMALL-SIGNAL CHARACTERISTICS

| | | | | | |
|------------------------------------|---|-----------|-----|-----|------------------|
| Current – Gain – Bandwidth Product | $(I_C = 10 \text{ mAdc}, V_{CE} = 20 \text{ Vdc}, f = 100 \text{ MHz})$ | f_T | 250 | – | MHz |
| Output Capacitance | $(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$ | C_{obo} | – | 4.5 | pF |
| Input Capacitance | $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$ | C_{ibo} | – | 10 | pF |
| Input Impedance | $(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$ | h_{ie} | 2.0 | 12 | k Ω |
| Voltage Feedback Ratio | $(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$ | h_{re} | 0.1 | 10 | $\times 10^{-4}$ |
| Small-Signal Current Gain | $(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$ | h_{fe} | 100 | 400 | – |
| Output Admittance | $(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$ | h_{oe} | 3.0 | 60 | μmhos |
| Noise Figure | $(I_C = 100 \text{ }\mu\text{Adc}, V_{CE} = 5.0 \text{ Vdc}, R_S = 1.0 \text{ k}\Omega, f = 1.0 \text{ kHz})$ | NF | – | 4.0 | dB |

SWITCHING CHARACTERISTICS

| | | | | | |
|--------------|--|-------|---|-----|----|
| Delay Time | $(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_{B1} = 1.0 \text{ mAdc})$ | t_d | – | 35 | ns |
| Rise Time | | t_r | – | 35 | ns |
| Storage Time | $(V_{CC} = 3.0 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc})$ | t_s | – | 225 | ns |
| Fall Time | $(V_{CC} = 3.0 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc})$ | t_f | – | 75 | ns |

2. Pulse Test: Pulse Width $\leq 300 \text{ }\mu\text{s}$; Duty Cycle $\leq 2\%$.

2N3906

ORDERING INFORMATION

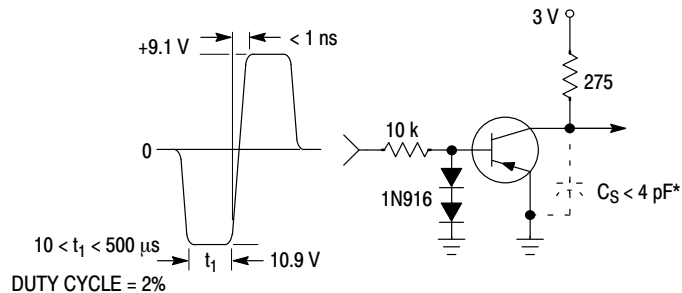
| Device | Package | Shipping† |
|-------------|--------------------|------------------------|
| 2N3906 | TO-92 | 5000 Units / Bulk |
| 2N3906G | TO-92 (Pb-Free) | 5000 Units / Bulk |
| 2N3906RL1 | TO-92 | 2000 / Tape & Reel |
| 2N3906RL1G | TO-92 (Pb-Free) | 2000 / Tape & Reel |
| 2N3906RLRA | TO-92 | 2000 / Tape & Reel |
| 2N3906RLRAG | TO-92 (Pb-Free) | 2000 / Tape & Reel |
| 2N3906RLRM | TO-92 | 2000 / Tape & Ammo Box |
| 2N3906RLRMG | TO-92 (Pb-Free) | 2000 / Tape & Ammo Box |
| 2N3906RLRP | TO-92 | 2000 / Tape & Ammo Box |
| 2N3906RLRPG | TO-92 (Pb-Free) | 2000 / Tape & Ammo Box |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit



* Total shunt capacitance of test jig and connectors

Figure 2. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS

— $T_J = 25^\circ\text{C}$
 - - - $T_J = 125^\circ\text{C}$



Figure 3. Capacitance

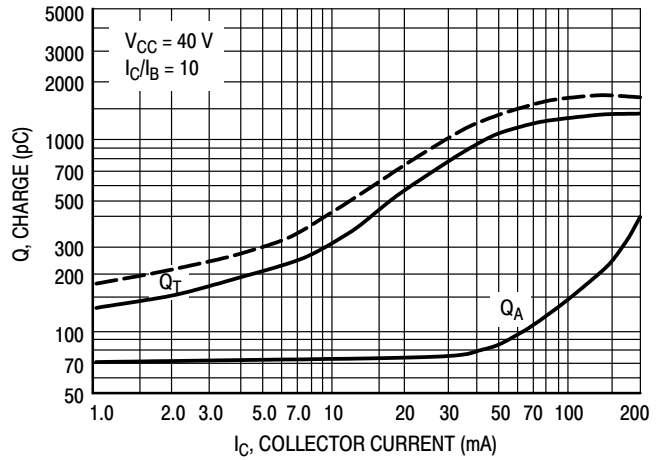


Figure 4. Charge Data

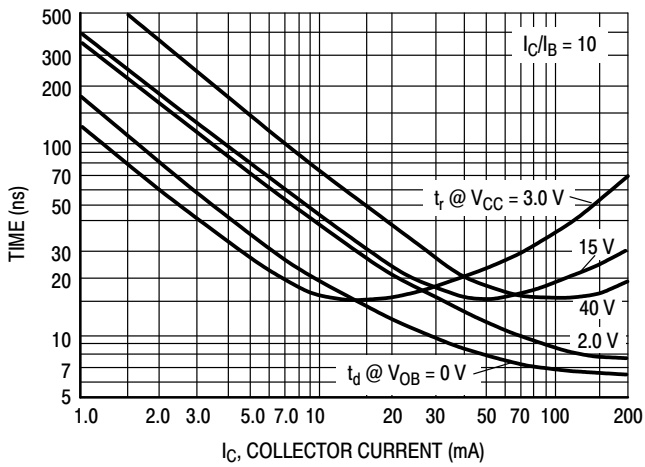


Figure 5. Turn-On Time

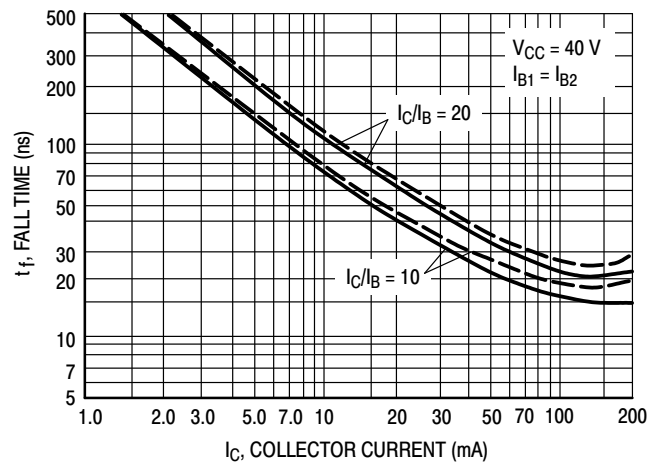


Figure 6. Fall Time

**TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS
NOISE FIGURE VARIATIONS**

($V_{CE} = -5.0$ Vdc, $T_A = 25^\circ\text{C}$, Bandwidth = 1.0 Hz)



Figure 7.



Figure 8.

h PARAMETERS

($V_{CE} = -10$ Vdc, $f = 1.0$ kHz, $T_A = 25^\circ\text{C}$)



Figure 9. Current Gain



Figure 10. Output Admittance



Figure 11. Input Impedance



Figure 12. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

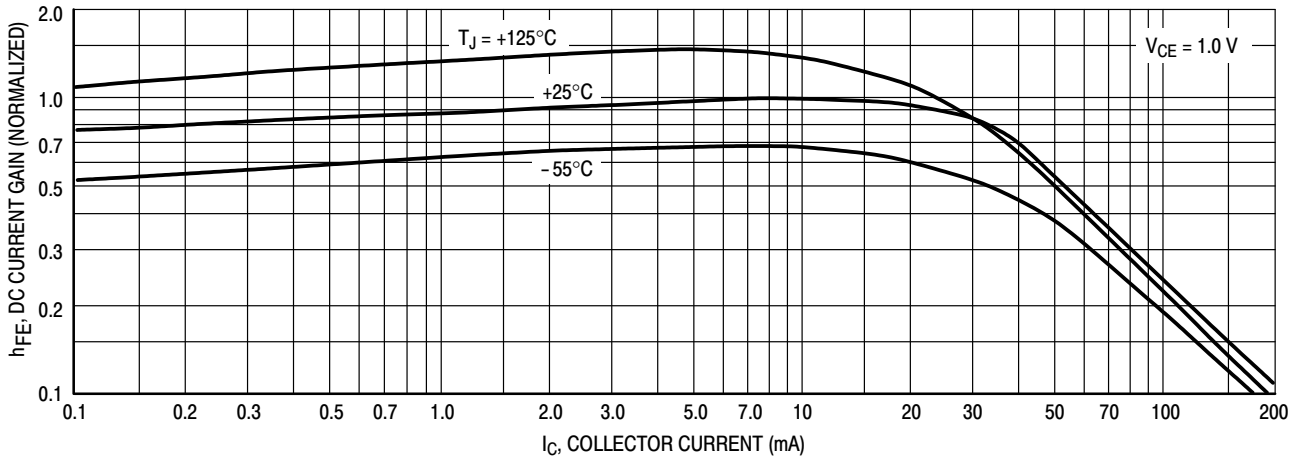


Figure 13. DC Current Gain

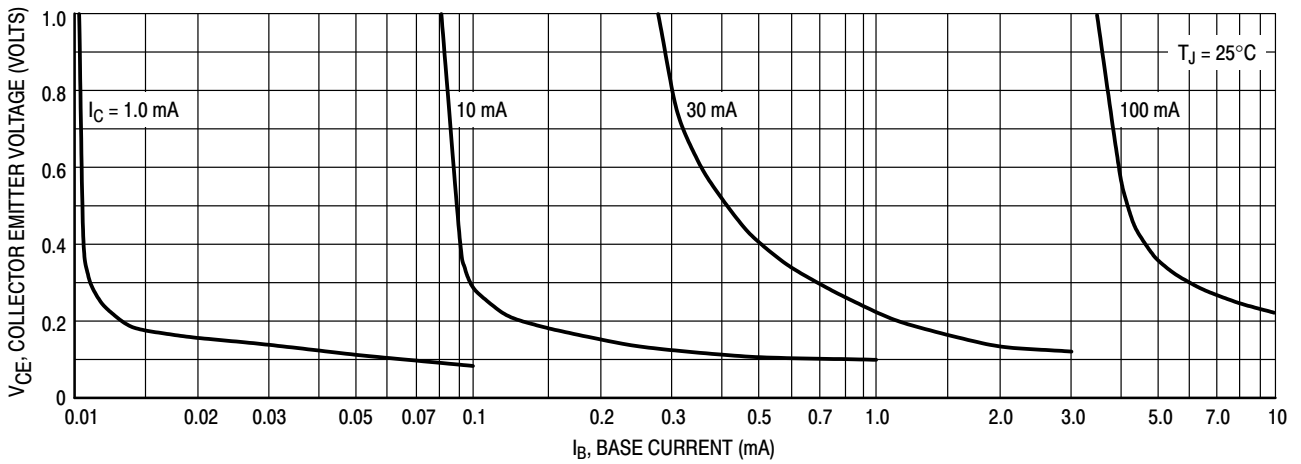


Figure 14. Collector Saturation Region



Figure 15. "ON" Voltages

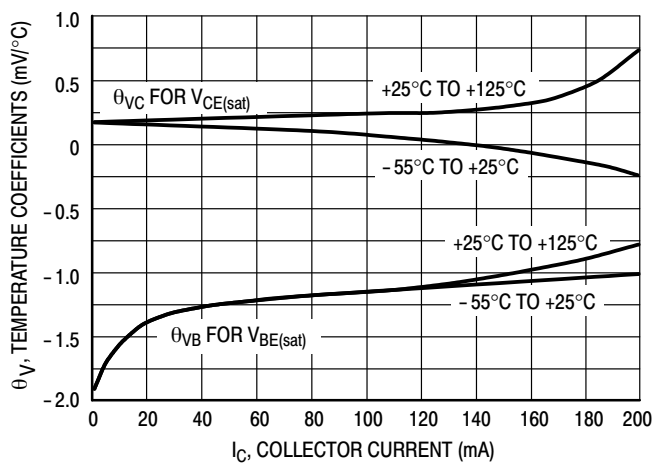


Figure 16. Temperature Coefficients

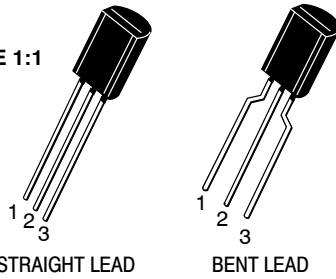
MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

ON Semiconductor®

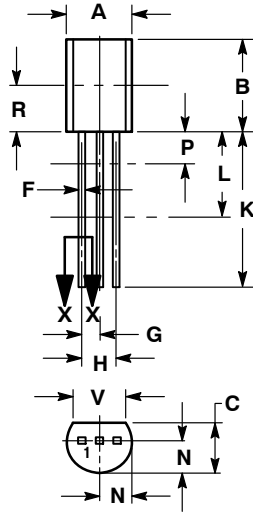


SCALE 1:1



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CASE 29-10
ISSUE A

DATE 08 MAY 2012

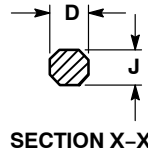


STRAIGHT LEAD

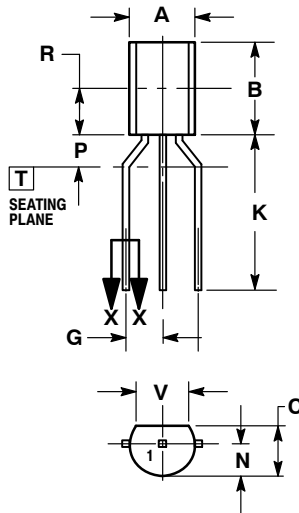
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.44 | 5.21 |
| B | 0.290 | 0.310 | 7.37 | 7.87 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.018 | 0.021 | 0.46 | 0.53 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.018 | 0.024 | 0.46 | 0.61 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.250 | --- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.135 | --- | 3.43 | --- |
| V | 0.135 | --- | 3.43 | --- |



SECTION X-X

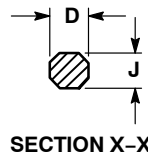


BENT LEAD

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.44 | 5.21 |
| B | 0.290 | 0.310 | 7.37 | 7.87 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.018 | 0.021 | 0.46 | 0.53 |
| G | 0.094 | 0.102 | 2.40 | 2.80 |
| J | 0.018 | 0.024 | 0.46 | 0.61 |
| K | 0.500 | --- | 12.70 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.135 | --- | 3.43 | --- |
| V | 0.135 | --- | 3.43 | --- |



SECTION X-X

STYLES ON PAGE 2

| | | |
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CASE 29-10
ISSUE A**

DATE 08 MAY 2012

- | | | | | |
|---|--|--|---|---|
| <p>STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR</p> | <p>STYLE 2: PIN 1. BASE 2. EMITTER 3. COLLECTOR</p> | <p>STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE</p> | <p>STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE</p> | <p>STYLE 5: PIN 1. DRAIN 2. SOURCE 3. GATE</p> |
| <p>STYLE 6: PIN 1. GATE 2. SOURCE & SUBSTRATE 3. DRAIN</p> | <p>STYLE 7: PIN 1. SOURCE 2. DRAIN 3. GATE</p> | <p>STYLE 8: PIN 1. DRAIN 2. GATE 3. SOURCE & SUBSTRATE</p> | <p>STYLE 9: PIN 1. BASE 1 2. EMITTER 3. BASE 2</p> | <p>STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE</p> |
| <p>STYLE 11: PIN 1. ANODE 2. CATHODE & ANODE 3. CATHODE</p> | <p>STYLE 12: PIN 1. MAIN TERMINAL 1 2. GATE 3. MAIN TERMINAL 2</p> | <p>STYLE 13: PIN 1. ANODE 1 2. GATE 3. CATHODE 2</p> | <p>STYLE 14: PIN 1. EMITTER 2. COLLECTOR 3. BASE</p> | <p>STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2</p> |
| <p>STYLE 16: PIN 1. ANODE 2. GATE 3. CATHODE</p> | <p>STYLE 17: PIN 1. COLLECTOR 2. BASE 3. EMITTER</p> | <p>STYLE 18: PIN 1. ANODE 2. CATHODE 3. NOT CONNECTED</p> | <p>STYLE 19: PIN 1. GATE 2. ANODE 3. CATHODE</p> | <p>STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE</p> |
| <p>STYLE 21: PIN 1. COLLECTOR 2. EMITTER 3. BASE</p> | <p>STYLE 22: PIN 1. SOURCE 2. GATE 3. DRAIN</p> | <p>STYLE 23: PIN 1. GATE 2. SOURCE 3. DRAIN</p> | <p>STYLE 24: PIN 1. EMITTER 2. COLLECTOR/ANODE 3. CATHODE</p> | <p>STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2</p> |
| <p>STYLE 26: PIN 1. V_{CC} 2. GROUND 2 3. OUTPUT</p> | <p>STYLE 27: PIN 1. MT 2. SUBSTRATE 3. MT</p> | <p>STYLE 28: PIN 1. CATHODE 2. ANODE 3. GATE</p> | <p>STYLE 29: PIN 1. NOT CONNECTED 2. ANODE 3. CATHODE</p> | <p>STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE</p> |
| <p>STYLE 31: PIN 1. GATE 2. DRAIN 3. SOURCE</p> | <p>STYLE 32: PIN 1. BASE 2. COLLECTOR 3. EMITTER</p> | <p>STYLE 33: PIN 1. RETURN 2. INPUT 3. OUTPUT</p> | <p>STYLE 34: PIN 1. INPUT 2. GROUND 3. LOGIC</p> | <p>STYLE 35: PIN 1. GATE 2. COLLECTOR 3. EMITTER</p> |

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